

Effect of the reference electrode size on the ionization instability in the plasma sheath of a small positively biased electrode

Y.P. Bliokh, Yu.L. Brodsky, Kh.B. Chashka, J. Felsteiner, and Ya.Z. Slutsker

Department of Physics, Technion, 32000 Haifa, Israel

It is well known that additional ionization in the vicinity of a positively biased electrode immersed into a weakly ionized plasma is responsible for a hysteresis in the electrode current-voltage characteristics and the current self-oscillations rise. Here we show both experimentally and theoretically that under certain conditions these phenomena cannot be correctly interpreted once considered separately from the reference electrode current-voltage characteristics. It is shown that small electrodes can be separated into three groups according to the relation between the electrode and the reference electrode areas. Each group is characterized by its own dependence of the collected current on the bias voltage.

I. INTRODUCTION

Phenomena related with a biased electrode (Langmuir probe) imbedded into a plasma have been studied beginning from the rise of plasma physics and are still in progress. The aim of the current investigation is the determination of the link between the measured current-voltage (C-V) electrode characteristics and the plasma parameters. For this purpose it is desirable to minimize the disturbances of the actual plasma parameters introduced by the probe.

However, there is a number of processes in the surrounding plasma caused by the probe presence that affect significantly the probe C-V characteristics. The probe C-V characteristics can be multi-valued and demonstrate a hysteresis-like behavior. Moreover, the current collected by the probe produces a set of instabilities (sheath-plasma instability¹, ionization induced instabilities^{2,3}, *etc*). As a result, the self-oscillations of the collected current rise even when the probe potential is kept constant.

There are several papers where the physical processes responsible for the excitation of the probe current oscillations are studied. However, the role of a mandatory element – the reference electrode for the probe – that closes the current circuit through the plasma, has to our knowledge not been adequately explored. In this paper the results of a detailed experimental investigation of the C-V characteristics of a positively charged probe are presented. Various probes have been studied whose area S_{pr} is small enough compared with the ion-collected electrode area (the reference electrode area) S_i :

$$S_{pr} \ll (m_e/m_i)^{1/2} S_i, \quad (1)$$

where m_e and m_i are the electron and ion masses, respectively. It will be shown that probes, whose areas meet the condition (1), can be separated into three groups: large, intermediate, and small probes. Each group is characterized by its own regime of interaction with the plasma. Affiliation with one group or another is determined by the relation between the C-V characteristics of the probe and the reference electrode which are connected in series via the plasma.

This paper is organized as follows. In section II, the experimental setup is described. The experimental results are presented in section III. A simple qualitative theoretical model and comparison with the experimental results are presented in section IV. The paper main results are summarized and discussed in section V.

II. EXPERIMENTAL SETUP

The experiments were mainly performed in a stainless steel vacuum chamber, having an inner diameter of 30 cm and a height of 8 cm (Fig. 1a). This chamber was equipped with two insulated tungsten filaments, one of them had 0.3 mm diameter and the other one – 0.1 mm. Both of them could be heated separately. The first one could be moved just when the chamber was open and the other one could be moved inside the chamber during experiments. The chamber was also equipped with a large surface probe, having an area $S = 7 \text{ cm}^2$, with a comparatively small ($S \simeq 0.6 \text{ cm}^2$) movable single probe and with a special holder for replaceable platinum probes of various lengths (1 – 25) mm and diameters (0.05 – 5) mm. The first (thicker) filament was used as a hot cathode. It was heated when a voltage pulse U_{heat} of 0.2 s duration was applied per each 5 s. To obtain a hot-cathode discharge and a plasma we applied a dc voltage either between the cathode and the grounded vacuum chamber or between the cathode and the large surface probe. In the latter case the discharge circuit was floating. The plasma density n_p and the electron temperature T_e were derived from the C-V characteristics of the above-mentioned probes. To verify these measurements we could also use the movable probe as a resonance probe⁴. To measure the plasma potential, the thin filament was used as a hot probe. To heat it, another dc source was used. To bias the small platinum probe we used either a dc power supply or a pulsed saw-tooth or rectangular voltage with pulse duration (150 – 200) μs (see Fig. 1a). Just a positive bias was used. The pulsed regime was used either to obtain its C-V characteristics in one “shot” or to prevent probe overheating if the collected current was too high. A thin glass plate of 3 cm diameter (not shown in Fig. 1a) could be placed between the hot cathode and the small positively biased probe to prevent direct current of the emitted electrons to this probe. A strong permanent magnet could be placed in various positions in the vicinity of the small probe in such a way that a magnetic field of (100 – 600) Gauss could be achieved there (see Fig. 1b). Also a set of spirals having a diameter of (5 – 20) mm and a 25 mm length could be placed around this probe (Fig. 1b). These spirals could also be biased either positively or negatively with respect to the probe. Some verifying measurements with just a hot cathode and a small probe could be carried out in a big vacuum chamber having a 66 cm diameter and a 100 cm length.

In our experiments we used either Ar at a pressure (0.5 – 5) mTorr or Xe at a pressure

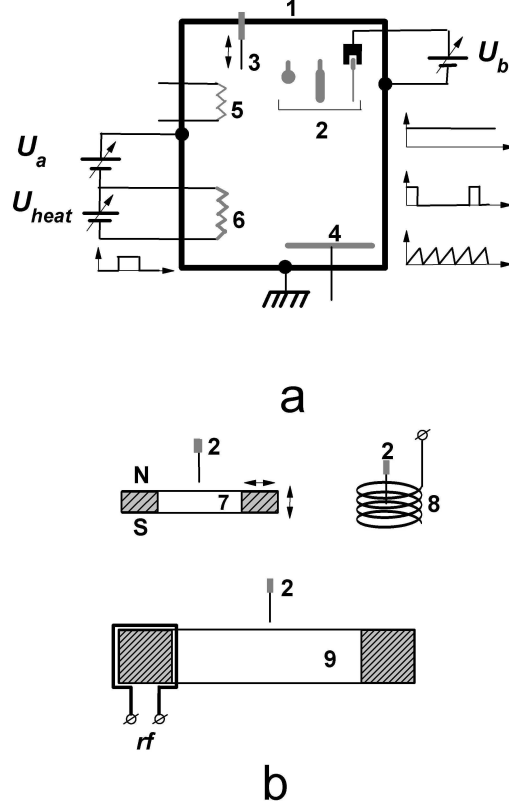


FIG. 1. a: 1 – vacuum chamber; 2 – set of replaceable probes; 3 – movable probe; 4 – large surface probe; 5 – a thin tungsten filament (hot probe); 6 – hot cathode; U_{heat} pulse duration – 0.2 s, repetition rate – 5 s, U_b – bias voltage, either dc, or rectangular pulses with 100 μ s duration and variable delay inside each discharge pulse, or continuous saw-tooth voltage with 200 μ s period. b: 7 – replaceable Nd magnet, inner diameter 5 cm, outer diameter 7.5 cm and thickness 0.6 cm; 8 – replaceable spiral around the probe; 9 - ferromagnetic core with 15 winding turns, inner diameter 10 cm, outer diameter 15 cm, thickness 2.5 cm.

(0.1 – 1) mTorr. Typically we applied an anode voltage $U_a \sim 100$ V in order to make sure that we work in a regime with the thermal limitation of the emitted current. This is reasonable in order to eliminate dependence of the plasma density n_p on U_a . Indeed in the range $U_a = (80 - 100)$ V, variations of the emitted current I_{emis} did not exceed 10%. On the other hand it was certain that in measurements with a large positive bias U_b on the small probe the value of U_a could be reduced to zero (the cathode directly connected to the chamber). In the investigated pressure range the plasma density n_p was found to be directly proportional to the pressure and the emitted current I_{emis} . The waveform of the

emitted current I_{emis} along with the ion saturation current I_i^{sat} , collected by the large surface probe, are shown in Fig. 2. The duration of the I_{emis} growth (~ 0.1 s) was long enough to consider a steady state plasma at any moment. In our experiments a 100 mA emission current corresponded to $n_p \leq 3 \cdot 10^9 \text{ cm}^{-3}$, $P = 3 \cdot 10^{-4} \text{ mTorr}$ and $T_e \sim (2 - 3) \text{ eV}$ with Xe gas. For the n_p measurements the discrepancy between the probe characteristics method and the resonance probe method did not exceed 15%. The fraction of fast electrons having energy $\sim eU_a$ never exceeded $(1 - 2)\%$. They appeared as a step in the ion part of the probe characteristics⁵. The emitted current I_{emis} as well as the probe current I_{pr} were measured with small current-view resistors. In order to study the influence of the ionization level there was a possibility to insert inside the vacuum chamber a single-core ferromagnetic inductively coupled (FIC) plasma source, driven by a powerful pulsed rf oscillator⁶ (see Fig. 1b). With this source the plasma density increased a few hundred times (at the same pressure) and the ionization rate could reach a value of $(20 - 30)\%$.

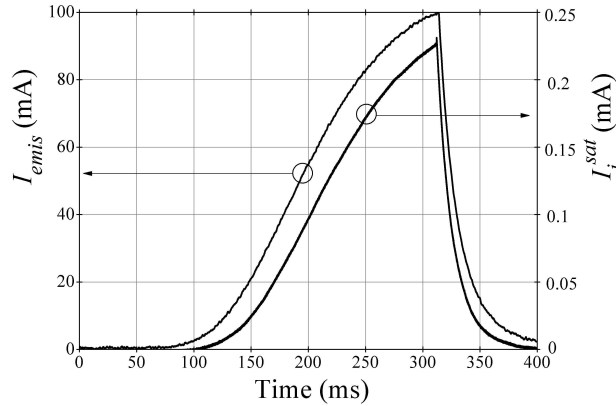


FIG. 2. (a) cathode emitted current I_{emis} , $U_{heat} = 10.5 \text{ V}$, $U_a = 100 \text{ V}$, Xe gas. (b) ion saturation current I_i^{sat} , collected by the surface probe ($S = 7 \text{ cm}^2$) and multiplied by factor $4 \cdot 10^2$.

III. EXPERIMENTAL RESULTS

When the positive bias U_b applied to any of the replaceable probes (Fig. 1a) was relatively low ($U_b < 25 \text{ V}$ for Xe and $U_b < 40 \text{ V}$ for Ar) the various C-V characteristics obtained with our set of probes, along with the measured potential fall $\Delta\varphi$ between the plasma and the probe, have already been described and explained long ago (see e.g. Ref. 7 and references therein). At a higher bias U_b a significant deviation could appear with various

combinations of the gas pressure P and probe sizes. Note, that at each “shot” the plasma density n_p increases from a very low value, when the Debye length r_d is large and the plasma sheaths near walls and electrodes could be comparable to the chamber sizes, to a value $n_p \geq 5 \cdot 10^9 \text{ cm}^{-3}$, when r_d becomes small compared to the smallest probes we used.

Large probe. — Thus, with the largest probe we used ($R = 5 \text{ mm}$) and at a fixed pressure, say $P = 0.3 \text{ mTorr}$ of Xe, the same probe characteristics could be also kept for $U_b > 25 \text{ V}$ just with one exception. Namely at very low plasma densities some irregular oscillations appeared in the probe current I_{pr} (see Fig. 3a). For higher n_p the behavior of I_{pr} and the potential fall φ_{pr} between the probe and the plasma during the pulse are very similar to the previous case when U_b was low (Fig. 3b). The maximal electron probe-collected current I_{pr} , saturated at high U_b , was equal to the sum of the emitted current I_{emis} and the total ion saturation current to the vacuum chamber walls (Fig. 3c). The total ion saturation current to the walls was derived as the geometrical ratio of the surface probe area (7 cm^2) and the total area of the metal vacuum chamber ($S_a \sim 2 \cdot 10^3 \text{ cm}^2$) multiplied by the ion saturation current to this probe I_i^{sat} (Fig. 2). In the case of the floating discharge circuit, i.e. when U_a was applied to the large surface probe instead of the chamber wall, I_{emis} was simply subtracted from this sum. It should be noted that at the densities when the irregularities of I_{pr} appear, the measurements showed that the thickness of the plasma sheath near the surfaces become comparable to the chamber size⁹. In our case it corresponds to $n_p \leq 3 \cdot 10^8 \text{ cm}^{-3}$, $I_{emis} \leq (5 - 8) \text{ mA}$ for Xe, and $I_{emis} \leq (10 - 15) \text{ mA}$ for Ar. The pressures were 0.3 mTorr and 1 mTorr for Xe and Ar respectively. Reducing drastically – in one order of magnitude – the pressure P at the same pulse of I_{emis} (at the same U_{heat}) it was possible to obtain these I_{pr} irregularities during the whole pulse of I_{emis} . Again, if the discharge circuit was floating, the maximal amplitude of the probe current irregular perturbations became smaller at the corresponding I_{emis} value. While these perturbations appeared in the electron probe current I_{pr} , no visible changes were seen neither in the emitted current I_{emis} (see Fig. 3) nor in the ion saturation current collected by a movable or surface probe. The latter means that the plasma density n_p kept constant.

Intermediate probe. — A very different behavior of I_{pr} could be observed when the probe sizes were reduced to $(0.6 - 1.2) \text{ mm}$. At very low pressures ($P < 0.05 \text{ mTorr}$) the same irregular oscillations could still be seen. In the pressure range $(0.1 - 0.8) \text{ mTorr}$ for Xe, when the probe bias exceeds 25 V , but still below a certain threshold, the probe C-V

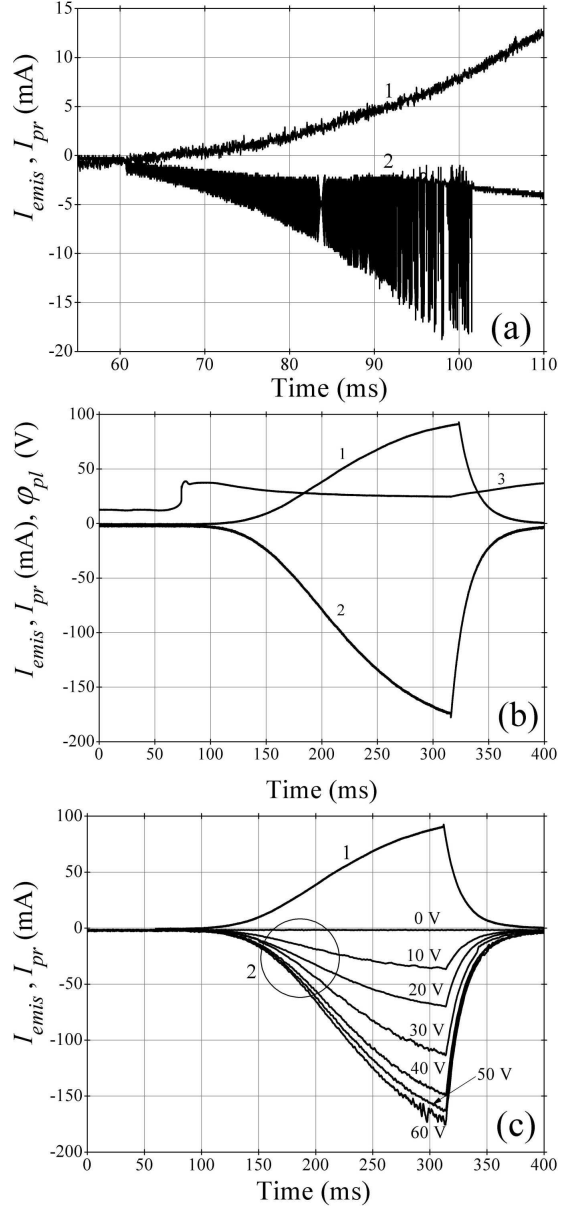


FIG. 3. 1 – emitted current I_{emis} ; 2 – probe current I_{pr} ; $U_a = 100$ V, $P = 0.3$ mTorr of Xe. (a) beginning of the discharge pulse, $U_b = 40$ V; the I_{pr} irregular perturbations are clearly seen. (b) 3 – full waveform of the potential fall between plasma and walls φ_{pl} (the plasma-probe potential $\varphi_{pr} = U_b - \varphi_{pl}$), waveforms of emitted current I_{emis} and probe current I_{pr} (the perturbations in the beginning are filtered out); $U_b = 60$ V. (c) I_{pr} saturation with U_b growth.

characteristics appeared as a prolongation of those for the lower voltage. They could be described by the theories mentioned above^{7,8}. On the other hand, when the bias voltage U_b reached a certain value, a single, few or many current spikes appeared in the probe current

I_{pr} . After adding further (2 – 4) V, periodic spikes filled the whole plasma pulse, i.e. in the wide range of $I_{emis} \propto n_p$ there appeared a probe-current instability. The corresponding U_b is recognized as the threshold U_{th} . Namely at $U_{th} = 58$ V and at $P = 0.3$ mTorr of Xe in the density range of $n_p \approx (4 \cdot 10^8 - 4 \cdot 10^9) \text{ cm}^{-3}$ the periodic spikes in the probe current I_{pr} are shown in Fig. 4a,c. Their period and duration kept approximately constant in the mentioned above density range and weakly depended on the bias voltage $U_b > U_{th}$. The waveform of I_{pr} in combination with the potential fall φ_{pl} between the plasma and the wall at the same I_{emis} , but at a bit higher $U_b = 61$ V, are shown in Fig. 4b. It is interesting to note, that these periodic spike oscillations, as a rule, started from a small but finite value of I_{emis} , the stage with irregular oscillations was usually skipped. On the other hand, in the narrow and unstable ranges of the bias U_b and pressure P it was possible to obtain irregular oscillations at low n_p which were switched to regular ones at higher n_p .

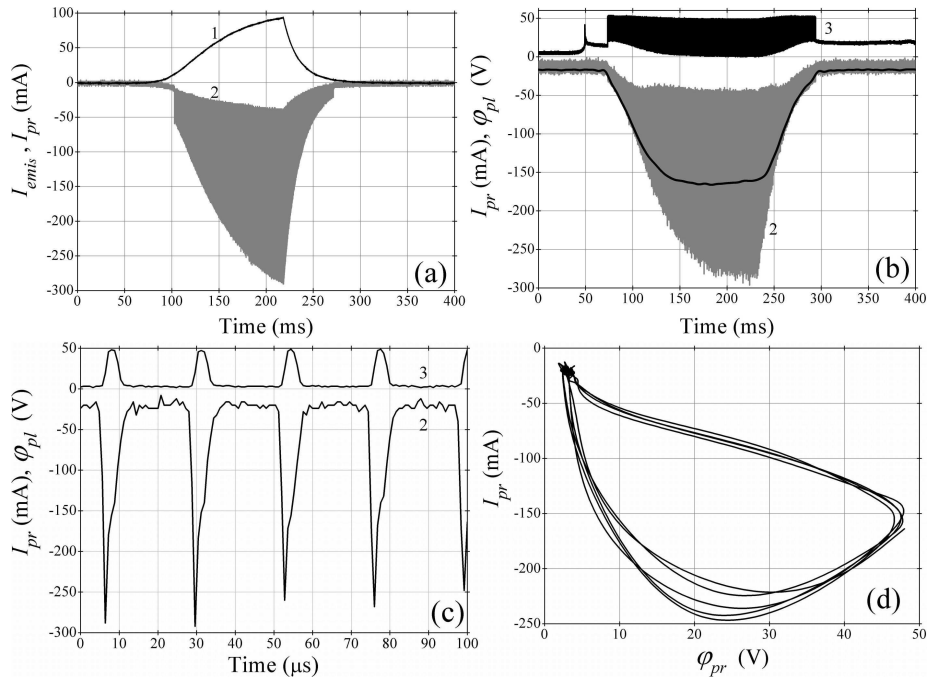


FIG. 4. Small probe: 1 mm diameter, 2 mm length, $P = 0.3$ mTorr of Xe, $U_a = 100$ V. (a) 1 – emission current I_{emis} ; 2 – probe current I_{pr} ; $U_b = 58$ V. (b) 3 – potential fall between the chamber wall and plasma φ_{pl} (potential fall between plasma and probe $\varphi_{pr} = U_p - \varphi_{pl}$), thick line – average value; $U_b = 61$ V. (c) the same, but expanded in the mid of pulse. (d) probe current I_{pr} vs φ_{pr} for the latter case.

These spikes were quite narrow compared to their period (see Fig. 4c). Typically the

spike duration was $\sim (1 - 1.5) \mu\text{s}$ for Ar and $\sim (2 - 3) \mu\text{s}$ for Xe while the spike period was $\sim (10 - 15) \mu\text{s}$ and $\sim (20 - 30) \mu\text{s}$, respectively. It should be noted that, as seen in Fig. 4c, the spikes of I_{pr} correspond to the minimal potential fall between the plasma and the probe: $\varphi_{pr} = U_b - \varphi_{pl}$, i.e. I_{pr} and φ_{pr} are in opposite phase. Also, as seen in Fig. 4d, there is a hysteresis in the probe C-V characteristics when this instability exists.

The threshold bias U_{th} definitely decreased with the increase of the pressure P : for Xe $U_{th} \approx 30 \text{ V}$ at $P = 1 \text{ mTorr}$, $U_{th} \approx 58 \text{ V}$ at $P = 0.3 \text{ mTorr}$ and $U_{th} \approx 80 \text{ V}$ at $P = 0.1 \text{ mTorr}$. A very similar tendency was obtained with Ar. At fixed pressure P the spikes amplitude increased monotonically with U_b and eventually reached its maximum which is equal to the total ion saturation current at the chamber wall. The average value of I_{pr} usually did not exceed 30% of the spike amplitude (see Fig. 4b). The minimal value of I_{pr} (see Fig. 4c) usually corresponded to the undisturbed (with no spikes) probe current, mentioned above^{7,8}. A further increase of the probe bias U_b led to qualitative changes of the probe current waveform (see Fig. 5): the spikes minima increase, the spikes amplitudes decrease, and a visible modulation appears in the ion saturation current I_i^{sat} collected by the surface probe (Fig. 5), i.e. there appears a modulation of the plasma density in the whole plasma volume.

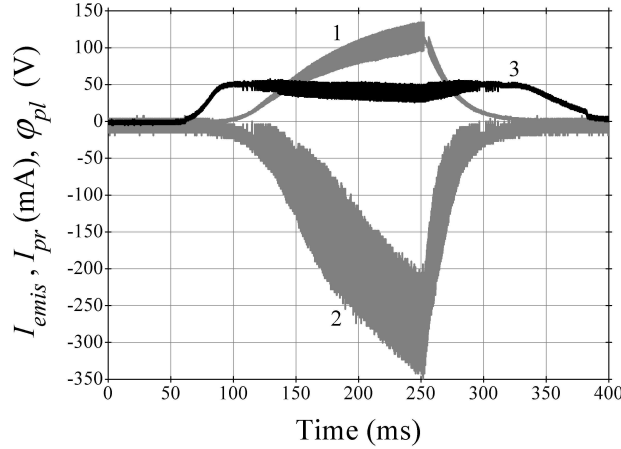


FIG. 5. Small probe: 1 mm diameter, 2 mm length, $P = 0.3 \text{ mTorr}$ of Xe, $U_a = 100 \text{ V}$, $U_b = 58 \text{ V}$. 1 – emission current I_{emis} ; 2 – probe current I_{pr} ; 3 – potential fall between the chamber wall and plasma φ_{pl} .

The above probe current instability could be “killed” by an external magnetic field of (600 – 800) Gauss. Such a magnetic field was obtained with a permanent magnet (Fig. 1b),

placed in the probe vicinity. In this case the ion gyrofrequency crudely corresponded to the oscillation frequency with no magnetic field: 35 kHz vs (30 – 40) kHz (Xe). Another way to stop this instability was to put a thin spiral around the probe (Fig. 1b). When the spiral radius was less than (5 – 7) mm, it surely stopped the instability independently whether the spiral was floated, grounded or biased up to ± 30 V. If the spiral radius exceeded (10 – 12) mm, no influence was seen. It means that the processes, determining the instability, were concentrated in the probe vicinity. Note, that the ion gyroradius ~ 1 cm corresponds to the ion energy ~ 5 eV, which is about $(0.2 - 0.3)\varphi_{pr}$, where φ_{pr} is the potential fall between the probe and the plasma corresponding to the moment when I_{pr} is maximal. On the other hand, the existence of this instability was definitely restricted by the ion current collected by the opposite, ion collecting electrode, i.e. by the external circuit. In the case of a small ion collecting area a big fraction of the probe bias U_b is applied to the plasma sheath near this electrode. Indeed when this electrode was too small, no instability appeared. This was directly confirmed when the ion collecting electrode we used was either the large surface probe ($S = 7 \text{ cm}^2$) or the insulated metal chamber cap ($S = 200 \text{ cm}^2$). In this case the hot-cathode discharge circuit (i.e. the plasma creating circuit) and the probe current circuit were separated and the probe circuit was floating.

It is interesting to note that a similar instability may appear not only in four- or three-electrode system, but also in two-electrode system. Thus, the same hot cathode and the same probe were placed in the large vacuum chamber (66 cm diameter and 100 cm length). The cathode was directly connected to the chamber (actually $U_a = 0$) and the probe was biased positively. This scheme is very similar to the one used more than two decades ago in experiments described by Stenzel^{1,10} where, we believe, similar probe-current spikes were noticed and later were recognized and studied³. In our two-electrode experiments, when U_b exceeded a certain threshold U_{th} , the periodic spikes appeared not only in the probe current but also in the emitted current I_{emis} (Fig. 6). This is contrary to the three- or four-electrode system, where I_{emis} kept constant. To obtain these oscillations the required U_b was approximately the same as in the case described in Refs. 1,10 and it was higher than in the case of three- or four- electrode system. Again, if the chamber (which is a big ion collector) was disconnected from the hot filament (cathode), no oscillation appeared in the probe circuit.

Small probe. — Further decreasing of the probe sizes again led to a drastic change of

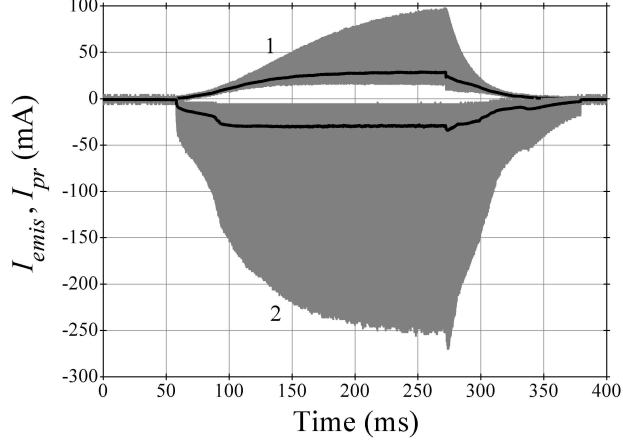


FIG. 6. Large vacuum chamber (66 cm diameter, 100 cm length); small probe (1 mm diameter, 2 mm length); $P = 0.3$ mTorr of Xe, the hot cathode is directly connected to the chamber; $U_a = 100$ V; 1 – emission current I_{emis} ; 2 – probe current I_{pr} . Thick lines – corresponding average values.

the probe characteristics. Thus, when the probe diameter was below 0.1 mm (with the same length of 2 mm), we could not find any self-consistent oscillations of the probe current I_{pr} . This was correct in the whole investigated ranges of pressure P and probe bias U_b for both sort of gases we used. On the other hand, above a certain bias voltage U_b the probe current I_{pr} jumped from its low value to a higher one. It happened almost independently of $I_{emis} \sim n_p$ (see Fig. 7a). The jump amplitude exceeds one order of magnitude. The threshold bias voltage U_{th} , when the jump occurs, was close to the threshold bias U_{th} , corresponding to the probe current instability occurrence in the described above experiments with the larger probe. Obviously, this was correct just for the same pressure P , sort of gas etc.

With further increasing U_b well above U_{th} , the probe current I_{pr} tended to saturate in the manner shown in Fig. 3c. Actually it also was limited by the total ion saturation current to the chamber wall. The threshold voltage U_{th} also decreased with the gas pressure rising up: at $P = 0.3$ mTorr of Xe, $U_{th} \approx 62$ V, and at $P = 0.6$ mTorr, $U_{th} \approx 48$ V. For Ar it was found that $U_{th} \approx 100$ V at $P = 1$ mTorr and $U_{th} \approx 70$ V at $P = 2$ mTorr. Unfortunately it was impossible to carry out these measurements in a wide range of pressures because a high U_b at low P as well as a high P at modest U_b could cause parasite sparking which, in turn, immediately led to the probe evaporation. The “switching” time of the probe current jumps was $\sim 20 \mu s$ for Xe (Fig. 7b) and $\sim 7 \mu s$ for Ar. These values exceeded by (3 – 4)

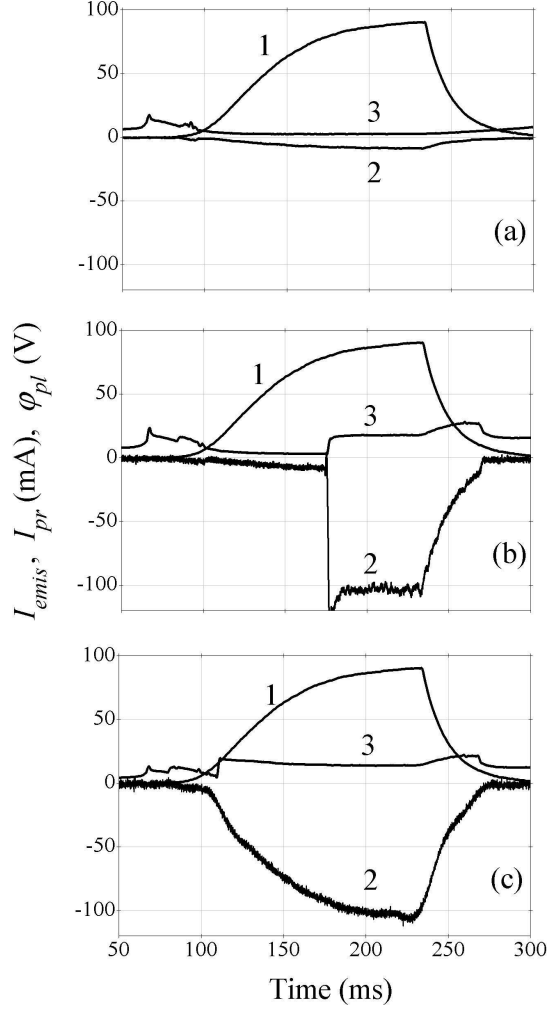


FIG. 7. Very small probe: 50μ diameter, 1 mm length, $P = 0.3$ mTorr of Xe, $U_a = 100$ V. (a) 1 – emitted current I_{emis} ; 2 – probe current I_{pr} ; 3 – potential fall between plasma and wall φ_{pl} ; $U_b = 59$ V. (b) the same, but $U_b = 61$ V. (c) the same, but $U_b = 62$ V.

times the spike duration when the probe current instability occurred.

To study the C-V characteristics of such a thin probe we applied a periodic saw-tooth voltage instead of the dc U_b (see Fig. 8). The saw-tooth duration was chosen as $\sim 200\mu s$. On the one hand this is much longer compared to the switching time, on the other hand this is much shorter compared to the plasma pulse. The latter means that during $200\mu s$ the plasma may be recognized as stationary. As it is clearly seen in Fig. 8b, the current jump starts at a substantially higher bias U_b compared to the bias U_b when the current falls down. It indicates the existence of hysteresis in the probe C-V characteristics (see Fig. 8c). A very similar hysteresis loop could be seen in a wide range of plasma densities during the plasma

pulse. When the pressure P was a bit reduced in order to bring this bias amplitude below U_{th} , no hysteresis was seen and the probe characteristics appeared as an almost straight line (see Fig. 8d), which is in a good agreement with the known theories for small probes^{7,8}.

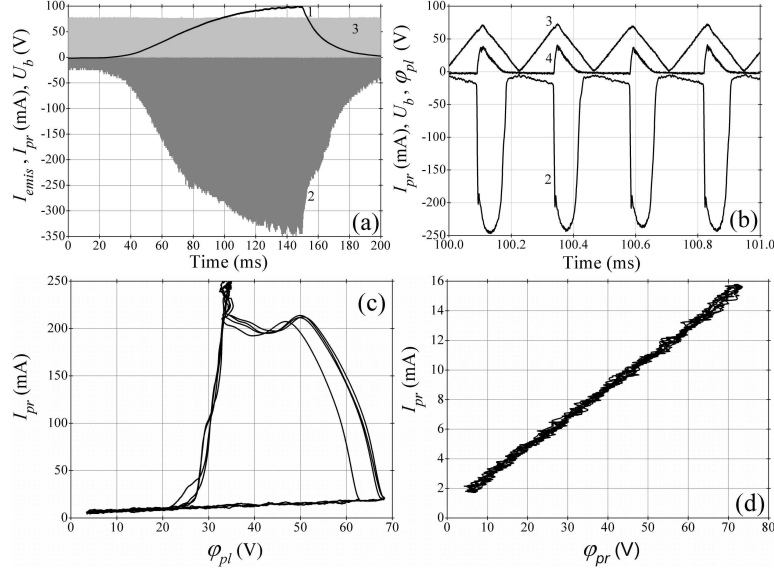


FIG. 8. Very small probe: 50μ diameter, 1 mm length, $U_a = 100$ V, U_b – periodic saw-tooth voltage of 200μ s period. (a) 1 – emitted current I_{emis} ; 2 – probe current I_{pr} ; 3 – bias voltage U_b ; $P = 0.3$ mTorr of Xe. (b) the same as above, but expanded around $t = 100$ ms; 4 – potential fall between plasma and wall φ_{pl} , $P = 0.3$ mTorr of Xe. (c) hysteresis of the probe characteristics; φ_{pr} – potential fall between plasma and probe: $\varphi_{pr} = U_b - \varphi_{pl}$; $P = 0.3$ mTorr of Xe. (d) the same, but $P = 0.25$ mTorr of Xe.

To complete this study we checked the qualitative influence of the ionization level on the probe characteristics. Namely we placed in the vacuum chamber the powerful pulsed single-core FIC plasma source⁶ (see Fig. 1b). It could work in the same pressure range and in our experiments we achieved ionization level $\leq 30\%$. The plasma density grew up to $\sim 3 \cdot 10^{12} \text{ cm}^{-3}$ during a 2 ms pulse. To prevent the probe damage, we biased the probe with a single variable positive voltage pulse with pulse duration of $\sim 100\mu\text{s} \ll 2$ ms. Typical waveforms of the probe current and plasma potential are shown in Fig. 9. In the investigated range of U_b the electron probe current could reach a few Amperes but the probe characteristics were smooth with no hysteresis, no instability of the probe current was seen and the potential fall φ_{pl} between the plasma and wall was always low.

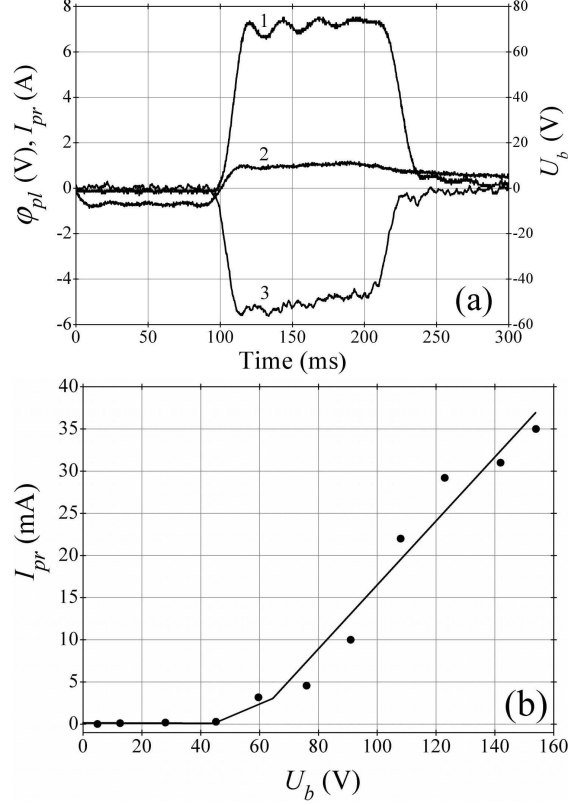


FIG. 9. Plasma density $n_p \simeq 3 \cdot 10^{12} \text{ cm}^{-3}$, $P = 0.3 \text{ mTorr}$ of Xe, ionization rate $\sim 30\%$; very small probe: 50μ diameter, 1 mm length. (a) 1 – bias voltage pulse U_b ; 2 – potential fall between plasma and wall ϕ_{pl} ; 3 – probe current I_{pr} . (b) electron current collected by the probe vs U_b .

IV. THEORETICAL MODEL AND ANALYSIS OF THE EXPERIMENTAL DATA

The experimental data show that the peculiarities of the probe C-V characteristics (instability, hysteresis) are the same either in three or four electrodes schemes. It means that the discharge circuit can be eliminated from the consideration.

A positively biased probe collects electron current I_{pr} from the surrounding plasma. The equivalent ion current I_{ref} is collected by a reference electrode (the chamber wall in the experiments). The current loops through an external circuit which maintains the voltage U_b between the electrodes. The probe and the reference electrode (thereafter cathode) currents depend on the voltage between them and the plasma: $I_{pr} = I_{pr}(\phi_{pr} - \phi_{pl})$ and $I_{ref} = I_{ref}(\phi_{pl} - \phi_{ref})$, where ϕ_{pr} , ϕ_{pl} , and ϕ_{ref} are the probe, plasma, and cathode potentials, respectively (thereafter $\phi_{ref} = 0$). Thus, taking into account that $\phi_{pl} + \phi_{pr} = U_b$, the

plasma potential φ_{pl} is determined by the condition:

$$I_{pr}(U_b - \varphi_{pl}) = I_{ref}(\varphi_{pl}). \quad (2)$$

In other words, the plasma potential and, consequently, the probe current are determined by both the probe and cathode C-V characteristics.

It is clear now that the dependence $I_{pr}(U_b)$, which we measure in our experiments, is close to the probe characteristics $I_{pr}(\varphi_{pl})$ when the plasma potential is small, $\varphi_{pl} \ll U_b$. This is possible when the ion-collecting area S_i (cathode area) is large enough compared with the probe area S_{pr} and Eq. (1) is satisfied.

When the bias voltage is large, $eU_b \gg T_e$, the effective collecting area S_{eff} around the small probe can exceed the probe geometric area and the condition in Eq. (1) should be written as follows:

$$S_i \gg (m_i/m_e)^{1/2} S_{eff}. \quad (3)$$

When the voltage U_b exceeds the ionization potential of the neutral gas, the ionization in the space-charge sheath around the probe can change drastically the collected current even if the electron impact ionization mean free path is large compared with the sheath thickness (see, e.g., Refs. 11-13). The probe C-V characteristics becomes three-valued with unstable middle branch and demonstrates hysteresis under a gradual increase and a subsequent decrease of the probe potential¹². The collected current on the stable upper and lower branches of the hysteresis loop can differ by more than an order of magnitude^{2,14}.

When the probe and the cathode C-V characteristics are known, the plasma potential φ_{pl} that satisfies Eq. (2) can be found graphically as it is depicted in Fig. 10. The cathode C-V characteristics is shown as a function of the potential φ , $I_{ref}(\varphi)$, whereas the probe characteristics is shown as a function of $U_b - \varphi$, $I_{pr}(U_b - \varphi)$. The intersection of these two curves defines the plasma potential φ_{pl} and the circuit current $I(U_b)$. Under the increase/decrease of the bias voltage U_b , the probe C-V characteristics curve is shifted right/left along the horizontal axis as a whole.

It is important to bear in mind that the probe characteristics shape depends on the probe dimension and form. Further we will consider small probes whose radii are comparable with the plasma Debye length. Such probes are characterized by the absence of a saturation current⁸. The characteristic values of the current which are inherent in the $I_{pr}(\varphi)$ dependence

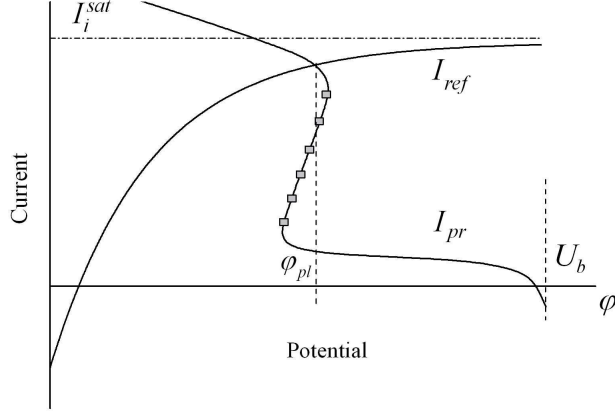


FIG. 10. Probe and reference electrode C-V characteristics. Gray squares mark the unstable branch of the characteristics.

(characteristic scale along the vertical axis in Fig. 10) increase/decrease monotonically with the increase/decrease of the probe radius.

Now, using this graphical representation, one can explain the experimental results described above. It is convenient to group the results in accordance with the probe radius: large, intermediate, and small probes.

Large probe. — When the probe radius is so large that the collected current exceeds the cathode saturation current even on the lower branch of the probe C-V characteristics, the intersection has the form depicted in Fig. 11. Independently of the bias voltage, the cathode characteristics intercepts only the lower *stable* branch of the probe characteristics. The experiments with the 5mm radius probe are related to this case (see Fig. 3).

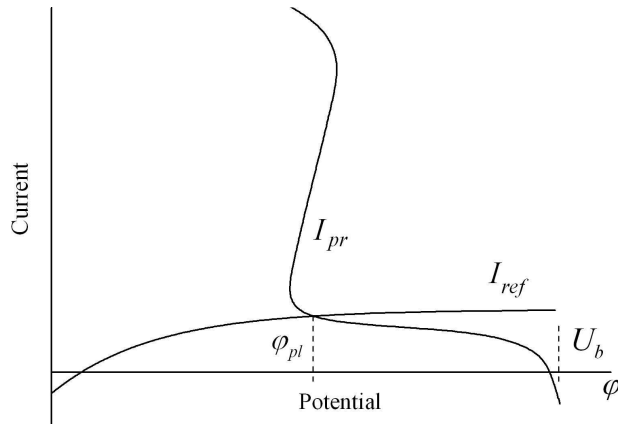


FIG. 11. Large probe.

Intermediate probe. — Under the probe radius decrease its C-V characteristics “shrinks”

along the vertical axis. The possible types of the intersections between the probe and cathode characteristics are shown in Fig. 12.

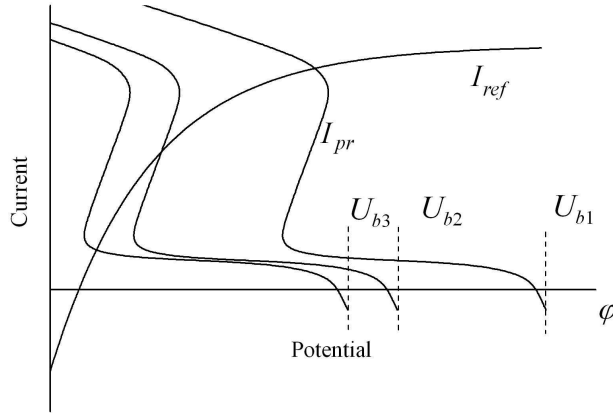


FIG. 12. Intermediate probe. $U_{b1} < U_{b2} < U_{b3}$.

The distinctive property of the intermediate probe is the following: there is a range of bias voltage values when the cathode characteristics $I_{ref}(\varphi)$ intercepts only the *unstable branch* of the probe characteristics $I_{pr}(U_b - \varphi)$ (curve $I_{pr}^{(2)}$, bias voltage U_{b2} in Fig. 12). It means that there are no stable solutions of Eq. (2) and self-oscillations of the current in the circuit appear when the bias voltage lies in the above-mentioned range. Note that jumps from the lower to the upper branch and backwards occur in different points of the probe C-V characteristics. Therefore, the dependence $I_{pr}[\varphi(t)]$ should demonstrate the hysteresis-like behavior.

The experiments with 0.6-1.2 mm radius probes demonstrate these peculiarities of the intermediate probe characteristics (see Fig. 4).

Small probe. — If the probe radius is so small that the collecting current is small compared with the ion saturation current for all voltages in the range of interest, the intersection between the C-V curves in Fig. 10 is located near the cathode floating potential (potential that corresponds to zero current). The intersection types for various bias voltages U_b are shown in Fig. 13.

Depending on the bias voltage, the cathode C-V characteristics intercepts either the lower branch of the probe characteristics (curve $I_{pr}^{(1)}$, bias voltage U_{b1} in Fig. 13), or three branches (curve $I_{pr}^{(2)}$, bias voltage U_{b2}), or the upper branch (curve $I_{pr}^{(3)}$, bias voltage U_{b3}). It is important to note that independently of the bias voltage the cathode characteristics always intercepts the *stable branches* (upper and lower branches, the intermediate branch is

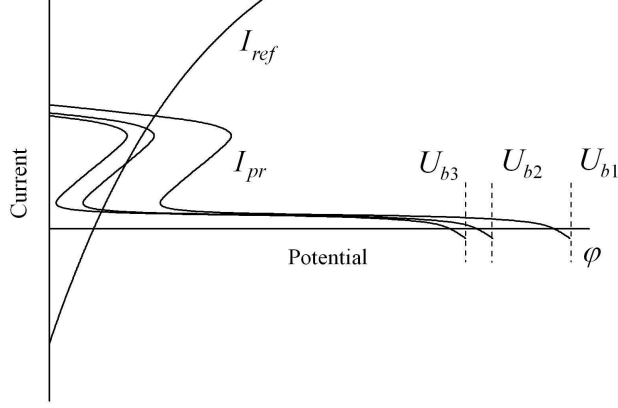


FIG. 13. Small probe. $U_{b1} < U_{b2} < U_{b3}$.

always unstable) of the probe characteristics. In this case there are stable solutions (either one or two) of Eq. (2) for all values of the bias potential. The C-V characteristics $I(U_b)$ demonstrates hysteresis under a gradual increase and a subsequent decrease of the potential U_b .

This qualitative analysis explains the experimental results related to the small (less than 0.1 mm diameter) probe presented in Figs. 14, 15, and 16.

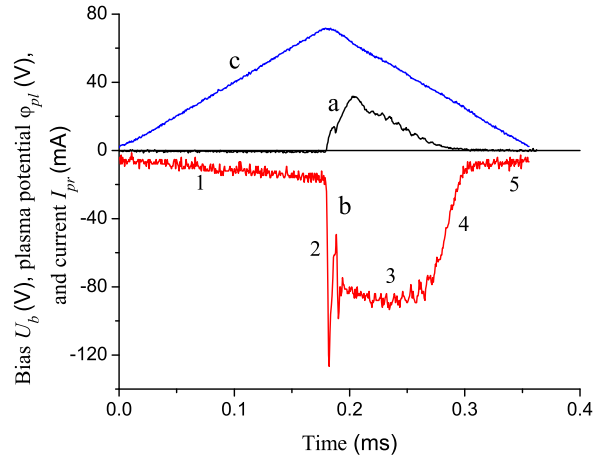


FIG. 14. Plasma potential φ_{pl} (b) and current I_{pr} (c) variations under a gradual increase and a subsequent decrease of the bias voltage U_b (a). The numerals that indicate the consecutive stages of the current variation are used below in Figs. 15 and 16.

The current circuit contains two elements: the plasma-probe sheath and the plasma-cathode sheath. The first one is characterized by a multi-valued C-V characteristics $I_{pr}(U_b -$

φ), whereas the C-V characteristics of the second one is a single-valued function $I_{ref}(\varphi)$. It means that under a gradual increase and a subsequent decrease of the potential U_b , the dependence $I_{ref}(\varphi)$ should be a single-valued function, despite the fact that the dependence $I_{pr}(U_b - \varphi)$ demonstrates hysteresis. This conclusion is confirmed by the experimental data shown in Figs. 15 and 16. Relatively small deviations from the single-valued dependence $I_{ref}(\varphi)$ (small hysteresis loops) reflect transient processes of the plasma-cathode sheath reconstruction caused by fast variations of the plasma potential φ under the “jumps” between the lower and upper branches of the probe C-V characteristics^{5,15}.

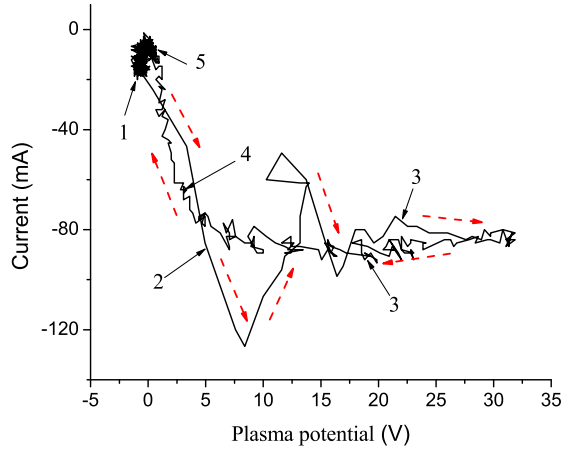


FIG. 15. The dependence $I_{ref}(\varphi_{pl})$ under a slow gradual increase and a subsequent decrease of the potential U_b . The numerals establish correspondence with the consecutive variation of the probe current shown in Fig. 14. The red dashed arrows show motion of the representative point in time.

The key element in the qualitative analysis above is the additional ionization inside the current-collecting sheath around the probe. Additional ions can essentially increase the sheath radius if the number of ions N_i in the sheath is comparable with the number of electrons N_e . Assuming that the ionization takes place in all the sheath volume, it is possible to make the following rough estimate of N_i . Any electron entering the sheath produces $n_0\sigma_i R$ ions, where n_0 is the gas density, σ_i is the ionization cross section, and R is the sheath radius. Thus, $N_i/N_e \sim (n_0\sigma_i R)(t_e/t_i)$, where $t_{e,i} \simeq R/v_{e,i}$ is the characteristic residence time of the particle in the sheath, and $v_{e,i}$ is the characteristic velocity of the particle. Because electrons and ions are accelerated by the same potential drop, $v_e/v_i = \sqrt{m_i/m_e}$, where m_i is the ion

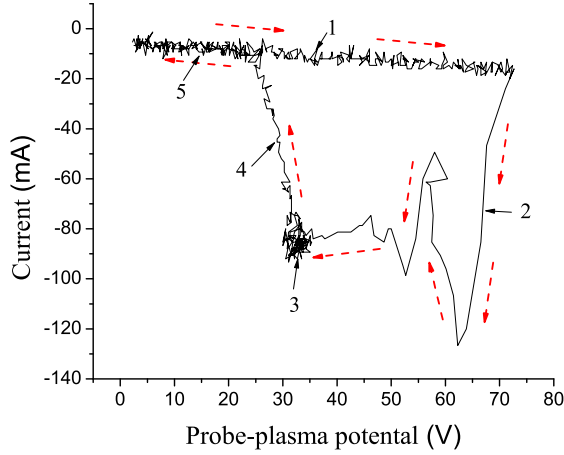


FIG. 16. The dependence $I_{pr}(U_b - \varphi_{pl})$ under a slow gradual increase and a subsequent decrease of the potential U_b . The meaning of the numerals and the red dashed arrows is the same as in Fig. 15

mass. Thus,

$$N_i/N_e \sim n_0 \sigma_i R \sqrt{m_i/m_e} \quad (4)$$

Under typical experimental conditions ($n_0 \sim 10^{13} \text{cm}^{-3}$, $\sigma_i \sim 4 \cdot 10^{-16} \text{cm}^2$, $\sqrt{m_i/m_e} \sim 4 \cdot 10^2$) the number of ions N_i in the sheath is comparable with the number of electrons N_e , $N_i/N_e \simeq 1$, when the sheath radius is of the order of 1 cm. This estimation is in a good agreement with the experimental data. Indeed, approximately the same radius $R \sim 1$ cm of the probe collecting area may be obtained directly from the amplitude of the probe current spikes (Fig. 4 – Fig. 8). This is correct in a wide range of plasma densities [emission currents $I_{emis} = (10 - 100)$ mA]. Experiments with various spirals placed around the probe showed also that the spiral did not disturb the current-collecting area when the spiral radius exceeds 1 cm.

The above estimation of the number of ions N_i in the sheath supposes implicitly that the neutral gas density n_0 is large enough so as to provide creation of this amount of ions. However, it does not always happen. In the vicinity of a small probe the electron density exceeds many times the plasma density due to the geometric focusing of the collected particles. The ionization rate in this region can be so large that the ionization degree n_p/n_0 would reach 100% during the ion residence time or even faster. In this case the number of ions N_i is always smaller than the number of electrons N_e in the sheath and the probe C-V characteristics is single-valued.

Let us estimate the sheath region where the ionization degree is small, $n_p/n_0 \ll 1$ and the condition

$$N_i/N_e \sim n_0 \sigma_i R \sqrt{m_i/m_e} \sim 1 \quad (5)$$

is satisfied. The ions production rate in a layer of radius r is described by the following equation:

$$\frac{dn_i(r)}{dt} = n_0 \sigma_i n_e(r) v_e(r), \quad (6)$$

where $n_e(r)$ and $v_e(r)$ are the collected electrons density and velocity, respectively. During the ion residence time $t_i \sim R/v_i$ the ionization degree reaches the value:

$$\frac{n_i(r)}{n_0} \sim n_0 \sigma_i n_e(r) v_e(r) \frac{R}{v_i} \sim n_0 \sigma_i R \sqrt{m_i/m_e} \frac{n_0}{n_p} \sqrt{T_e/eU_b} \frac{R^2}{r^2}. \quad (7)$$

Here the particles flux conservation law $n_e(r) v_e(r) r^2 = \text{const} = n_p \sqrt{T_e/m_e} R^2$ is used.

When the condition (5) is satisfied, the ionization degree is small, and $n_p/n_0 \ll 1$ in a sheath region of radius

$$r \gg R \left(\frac{n_p}{n_0} \right)^{1/2} \left(\frac{T}{eU_b} \right)^{1/4} \equiv r_c. \quad (8)$$

It follows from Eq. (8) that the region, where the neutral gas density cannot provide production of the required amount of ions, occupies a considerable part of the sheath volume when the plasma density is large enough, all other factors being the same.

In the set of experiments where plasma is created by discharge with a hot cathode ($n_p \simeq 3 \cdot 10^9 \text{ cm}^{-3}$) the ratio $r_c/R \simeq 10^{-2}$ is small and the probe C-V characteristics is multi-valued. In contrast, in the experiments with the FIC plasma source ($n_p \simeq 3 \cdot 10^{12} \text{ cm}^{-3}$) this ratio is large, $r_c/R \simeq 0.5$, and hence the probe current is stable and self-oscillations are not observed despite that the potential fall between the probe and the plasma could significantly exceed the ionization potential.

V. SUMMARY

The characteristics of small positively biased electrodes (probes) immersed into a plasma have been studied. These probes were much smaller than the reference electrode size divided by the square root of the ion/electron mass ratio. The electron current branch of the C-V characteristics of such probes is widely used to measure the local plasma parameters. Additional ionization of neutral gas by electrons accelerated in the space-charge sheath

around the probe could significantly expand the sheath thickness. However, we were focused on the case, when the sheath thickness still remains small compared to the whole plasma and reference electrode sizes. It should be emphasized that in our experiments this additional ionization inside the sheath does not change the plasma parameters in the whole volume. When the probe dimension is large compared to the sheath thickness, the sheath expansion does not affect the current collected by the probe from the plasma. On the other hand, near a very small probe the sheath expansion induced by the ionization leads to considerable increase of the collected current.

The probe current loop is closed through the ion-collecting electrode (cathode) having its own C-V characteristics. The potential fall between the cathode and the plasma should rise to support the increasing current. The plasma potential growth changes the potential drop between the probe and the plasma, and the probe current should be changed in accordance with the probe C-V characteristics. Thus, the current is determined by the relation between the probe and the reference electrode C-V characteristics.

It has been shown both experimentally and theoretically that these small probes can be separated into three groups according to the probe dimensions. Every group is characterized by its particular dependence of the collected current on the bias voltage. The current collected by the “large” probes increases monotonically and continuously with the voltage growth. The probes with an “intermediate” size are characterized by excitation of strong periodic spike-like oscillations under a constant bias voltage. The current collected by the “small” probes is stable, but changes stepwise under certain bias voltage values and demonstrates hysteresis under a gradual increase and a subsequent decrease of the bias voltage. Both oscillations and current steps are caused by additional ionization in the probe vicinity. Note, that the same probe can be treated as either large, intermediate, or small depending on the value of the reference electrode area. Ignoring the possibility of probe-current instability, neither the plasma density nor the electron temperature could be measured correctly by this probe even if the oscillations are filtered out, averaged etc. In the case of stepwise jumps of the probe current the upper current level does not reflect directly the plasma parameters in the place where the probe is located.

In conclusion, we have demonstrated that under certain conditions, phenomena related with Langmuir probes cannot be correctly interpreted once considered separately from the reference electrode characteristics.

REFERENCES

- ¹R.L. Stenzel, Phys. Fluids B **1**, 2273 (1989).
- ²T.Klinger, F. Greiner, A. Rohde, and A. Piel, Phys. Plasmas **2**, 1822 (1995).
- ³R.L. Stenzel, C. Ionita, and R. Schrittwieser, Plasma Sources Sci. Technol. **17**, 035006 (2008).
- ⁴V.E. Golant, *Sverkhvysokochastotnye metody issledovaniya plazmy* (Nauka, Moscow, 1968) chap. 8, p. 217 (in Russian).
- ⁵Y.P. Bliokh, Yu.L. Brodsky, Kh.B. Chashka, J. Felsteiner, and Ya.Z. Slutsker, J. Appl. Phys. **103**, 053303 (2008).
- ⁶Y.P. Bliokh, J. Felsteiner, Ya.Z. Slutsker, and P.M. Vaisberg, Appl. Phys. Lett. **85**, 1484 (2004); Y.P. Bliokh, Yu.L. Brodsky, Kh.B. Chashka, J. Felsteiner, and Ya.Z. Slutsker, J. Appl. Phys. **107**, 015009 (2010).
- ⁷F.F. Chen, in *Plasma Diagnostics Techniques*, Eds. R.H. Huddleston and S.L. Leonard (Academic, NY, 1965), chap. 4.
- ⁸H.M. Mott-Smith and I. Langmuir, Phys. Rev. **28**, 727 (1926); I.B. Bernstein and I.N. Rabinowitz, Phys. Fluids **2**, 112 (1959); F. Chen, J. Nucl. Energy, Part C **7**, 47 (1965); J.E. Allen, Phys. Scr. **45**, 497 (1992).
- ⁹S. Chiriac, D.G. Dimitriu, and M. Saduloviciu, Phys. Plasmas **14**, 072309 (2007).
- ¹⁰R.L. Stenzel, Phys. Rev. Lett. **60**, 704 (1988).
- ¹¹D.L. Cook and I. Katz, J. Spacecraft **25**, 132 (1987).
- ¹²C. Ionita, D.-G. Dimitriu, and R.W. Schrittwieser, Int. J. Mass Spectrom. **233**, 343 (2004).
- ¹³L. Conde, C. Ferro Fontan, and J. Lambas, Phys. Plasmas **13**, 113504 (2006).
- ¹⁴M. Strat, G. Strat, and S. Gurliu, Phys. Plasmas **10**, 3592 (2003).
- ¹⁵Y.P. Bliokh, J. Felsteiner, Ya.Z. Slutsker, and P.M. Vaisberg, Phys. Plasmas **9**, 3311 (2002).